

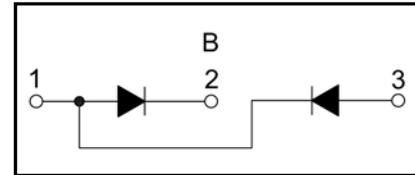
PRODUCT FEATURES

- Glass Passivated Chip
- Aluminum Oxide Ceramic Isolated Metal Baseplate
- Low Reverse Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Inductance Package



APPLICATIONS

- Field Supply For DC Motors
- Line Rectifiers For Transistorized AC Motor Controllers
- Non-controllable Rectifiers For AC/DC Converter



ABSOLUTE MAXIMUM RATINGS

$T_C=25^\circ\text{C}$ unless otherwise specified

| Symbol | Parameter | Test Conditions | Max. | Unit |
|--------------|--------------------------------------|--|-------------|-----------------------|
| V_{RRM} | Repetitive Reverse Voltage | | 1600 | V |
| $I_{F(AV)}$ | Average Forward Current | $T_C=75^\circ\text{C}$ Rectangular, $d=0.5$ | 240 | A |
| $I_{F(RMS)}$ | RMS Forward Current | $T_C=75^\circ\text{C}$ Rectangular, $d=0.5$ | 340 | A |
| I_{FSM} | Non-Repetitive Surge Forward Current | $T_J=45^\circ\text{C}$, $t=10\text{ms}$, 50Hz, Sine | 10000 | A |
| | | $T_J=45^\circ\text{C}$, $t=8.3\text{ms}$, 60Hz, Sine | 10700 | A |
| I^2t | I^2t (For Fusing) | $T_J=45^\circ\text{C}$, $t=10\text{ms}$, 50Hz, Sine | 352 | KA^2s |
| | | $T_J=45^\circ\text{C}$, $t=8.3\text{ms}$, 60Hz, Sine | 351 | KA^2s |
| P_D | Power Dissipation | | 890 | W |
| T_J | Junction Temperature | | -40 to +150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature Range | | -40 to +125 | $^\circ\text{C}$ |
| V_{isol} | Insulation Test Voltage | AC, 50Hz, $t=1\text{min}$ | 3000 | V |
| Weight | | | 165 | g |

ELECTRICAL AND THERMAL CHARACTERISTICS

$T_C=25^\circ\text{C}$ unless otherwise specified

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|-----------------|----------------------------------|--|------|------|------|---------------------------|
| I_{RM} | Reverse Leakage Current | $V_R=1600\text{V}$ | -- | -- | 500 | μA |
| | | $V_R=1600\text{V}$, $T_J=125^\circ\text{C}$ | -- | -- | 10 | mA |
| V_F | Forward Voltage | $I_F=500\text{A}$ | -- | 1.3 | 1.40 | V |
| | | $I_F=500\text{A}$, $T_J=125^\circ\text{C}$ | -- | 1.25 | -- | V |
| V_{T0} | For power-loss calculations only | | | | 0.8 | V |
| r_T | | | | | 1.2 | $\text{m}\Omega$ |
| $R_{\theta JC}$ | Thermal Resistance | Junction-to-Case | -- | -- | 0.14 | $^\circ\text{C}/\text{W}$ |

MECHANICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|--------|-------------------|------------------|------|------|------|-------|
| Torque | Module-to-Sink | Recommended (M6) | 3 | | 5 | N · m |
| Torque | Module Electrodes | Recommended (M6) | 3 | | 5 | N · m |

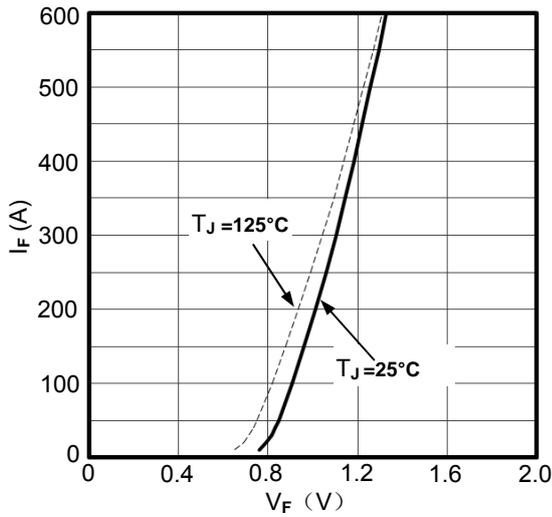


Figure1. Forward current vs.voltage drop per diode

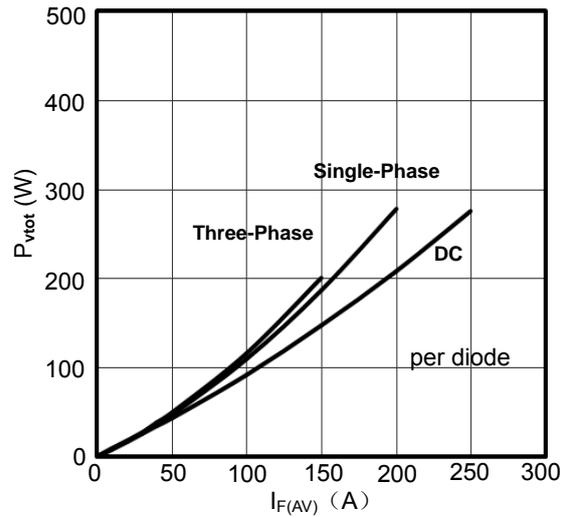


Figure2. Power dissipation vs. $I_{F(AV)}$

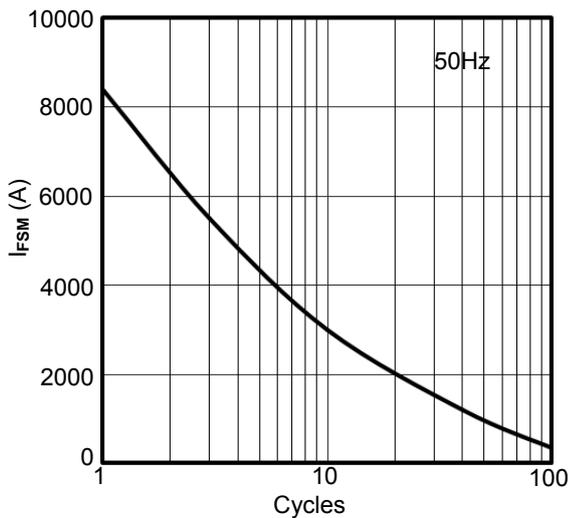


Figure3. Max Non-Repetitive Forward Surge Current

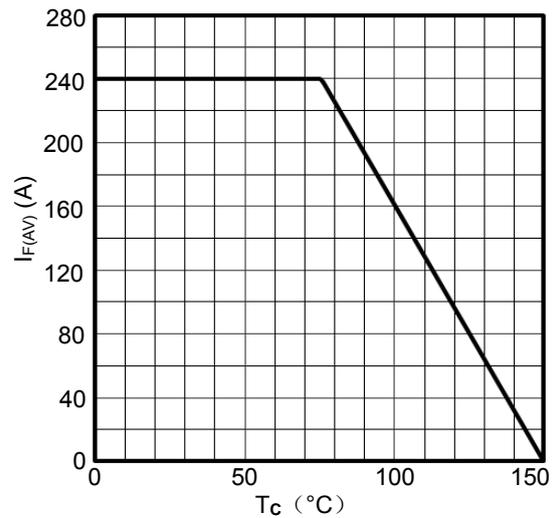


Figure4. Forward current vs. Case temperature

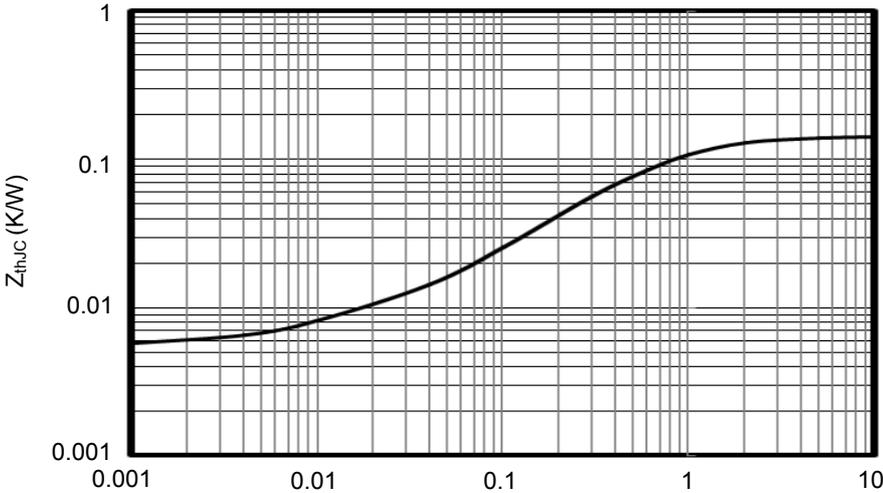


Figure5. Transient Thermal Impedance

Package Outline (Dimensions in mm)

